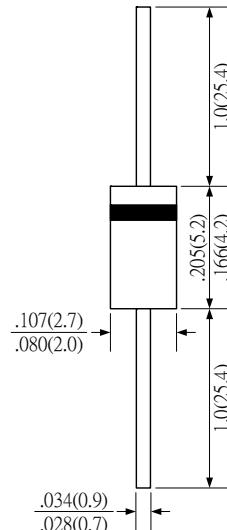


Power Schottky Rectifier - 1Amp 150~200Volt

Features

- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability
- Epitaxial construction

D0-41



Mechanical data

- Case : Molded plastic
- Epoxy : UL 94V-0 rate flame retardant
- Lead : Axial leads, solderable per MIL-STD-202, method 208 guaranteed
- Polarity : Color band denotes cathode end
- Mounting position : Any
- Weight : 0.34 grams

Maximum ratings and Electrical characteristics

TYPE	SB1150	SB1200	UNIT
Maximum Recurrent Peak Reverse Voltage	150	200	V
Maximum RMS Voltage	105	140	V
Maximum DC Blocking Voltage	150	200	V
Maximum Average Forward Rectified Current	1.0		A
Peak Forward Surge Current, 8.3ms single half sine-wave superimposed on rated load(JEDEC method)	30		A
Maximum Instantaneous Forward Voltage at 1.0A	0.88	0.90	V
Maximum DC Reverse Current at Rated DC Blocking Voltage	Ta = 25°C Ta = 100°C	0.01 10	mA
Typical Junction Capacitance	110		pF
Typical Thermal Resistance R _{θJA}	30		°C/W
Operating Temperature Range T _J	-50 to +175		°C
Storage Temperature Range T _{STG}	-50 to +150		°C

Note: Pulse Test : 380μs pulse width, 2% duty cycle

September 2008 / Rev.6.2

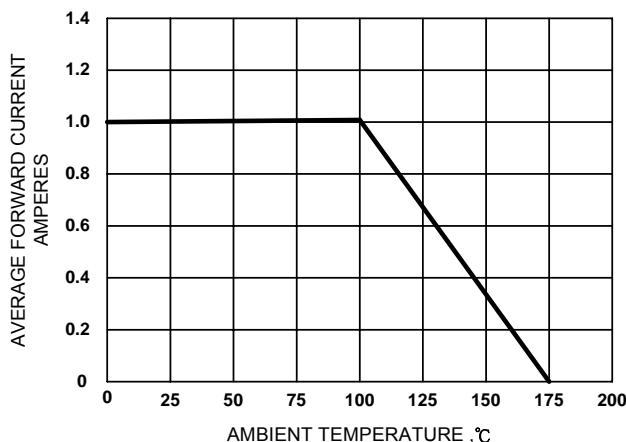


Figure 1. Forward Current Derating Curve

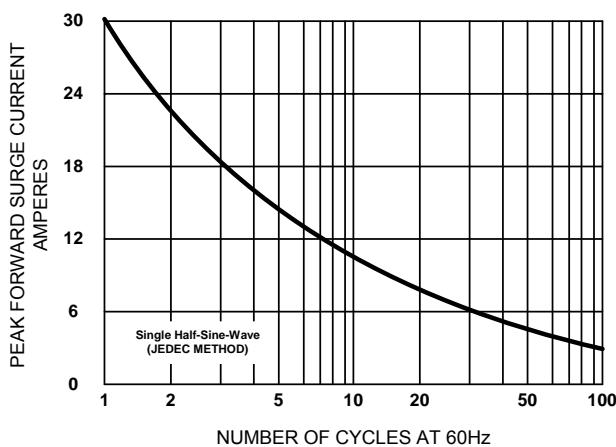


Figure 2. Maximum Non-repetitive Surge Current

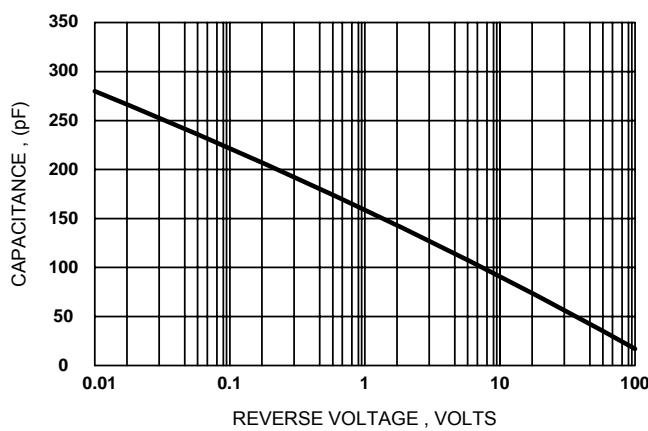


Figure 3. Typical Junction Capacitance

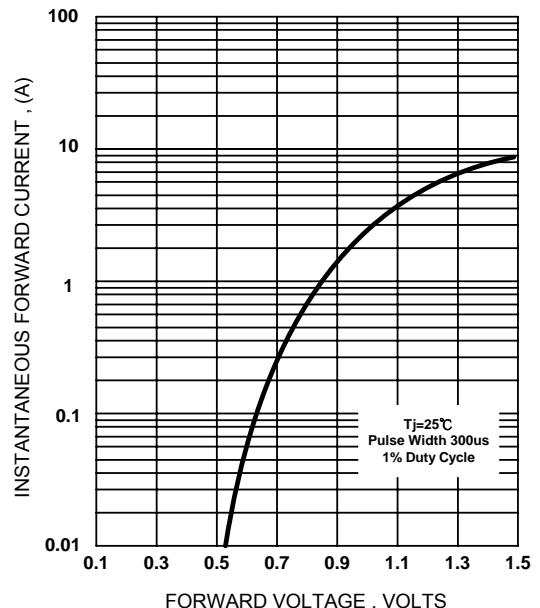


Figure 4. Typical Forward Characteristics

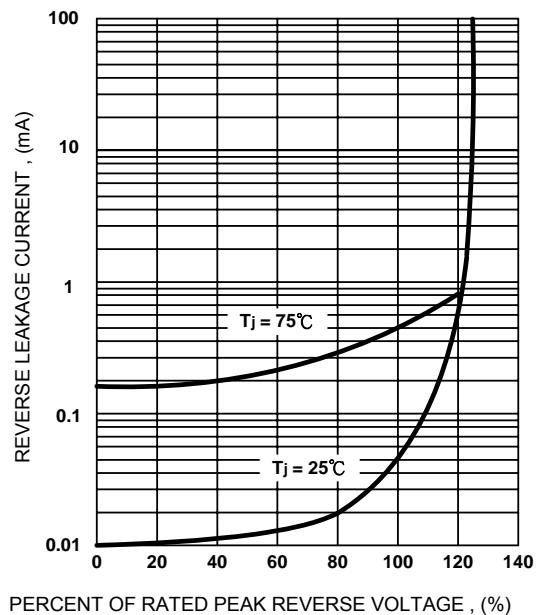


Figure 5. Typical Reverse Characteristics



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